

34th European Mask and Lithography Conference EMLC 2018

MINATEC Conference Center, Grenoble, France
Monday, June 18th – Wednesday, June 20th 2018

Overview of Manuscripts for SPIE Proceedings Vol. 10775

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and

Presentation Downloads for EMLC2018 Website “Exclusive”

Monday, June 18th, 2018

14:00-17:00 **The EMLC2018 Tutorial Class**

14:00 **Welcome and Introduction of the 1st Tutorial Speaker**
Uwe Behringer, UBC Microelectronics, EMLC2018 Conference Chair

14:05-15:20 **Inspection Challenges in the EUV Area**
Aviram Tam, Applied Materials PDC, Israel

This Tutorial will cover the use cases for blank inspection, pattern inspection, outgoing inspection, and the possible solution for DUV mask inspection, eBeam MI, Actinic blank inspection, on-wafer qualification, and how those evolve in each of the different scenarios for pellicle (no pellicle / detachable / 13.5nm only / 193nm friendly).

15:20-15:40 Coffee Break

15:40 **Introduction of the 2nd Tutorial Speaker**
Jo Finders, ASML Netherlands B.V., EMLC2018 Conference Chair

15:45-17:00 **Review of OPC / RET / SMO**
Paul van Adrichem, ASML Netherlands B.V., Veldhoven, Netherlands
Presentation download to EMLC2018 Exclusive: Tutorial_01

This tutorial will provide an overview of advanced Optical Proximity Correction, Resolution Enhancement Technology as well as Source-Mask-Optimization.

17:00 **Get-Together and 1st Poster Session**
Uwe Behringer, Chair of EMLC2018, welcomes the participants and invites them to join the Get-Together concurrently with the first Poster Session.

17:05-18:00 **1st Part of Poster Presentations**
Chair: U. Behringer, UBC Microelectronics, Ammerbuch, Germany
Co-Chair: R. Seltmann, GLOBALFOUNDRIES, Dresden, Germany

As to the Poster Presentations: pls. see Session 5

Tuesday, June 19th, 2018

- 09:00 **Welcome and introduction**
U. Behringer, UBC Microelectronics, EMLC2018 Conference Chair
[Presentation download to EMLC2018 Exclusive: Welcome_01](#)
- 09:10 **City of Grenoble Welcome:**
Grenoble-Alpes Métropole Welcomes You (Invited)
M.-J. Salat,
Grenoble-Alpes Métropole, Grenoble, France
[Presentation download to EMLC2018 Exclusive: Welcome_02](#)
- 09:30-10:25 **Session 1 - 1st Plenary**
Chair: J. Finders, ASML Netherlands B.V., EMLC2018 Conference Chair
Co-Chair: J. Wiley, ASML US Inc., Santa Clara, USA
- 09:30 **Technology for Optical Sensors (Keynote)**
O. Noblanc,
STMicroelectronics, Crolles, France
[Presentation download to EMLC2018 Exclusive: S01_01](#)
- 10:00 **Best Poster of BACUS 2017:**
Transparent and conductive backside coating of EUV Lithography Masks for ultrashort pulse Laser Correction (Invited)
R. A. Maniyara^a, D. S. Ghosh^a, V. Pruneri^{a,b}
a) ICFO - Institut de Ciències Fotòniques, The Barcelona Institute of Science and Technology, Barcelona, Spain
b) ICREA - Institució Catalana de Recerca i Estudis Avançats, Barcelona, Spain
- 10:25-10:50 Coffee Break
- 10:50-12:10 **Session 2 - 2nd Plenary**
Chair: R. Galler, EQUIcon, Jena, Germany
Co-Chair: U. Buttgerit, Carl Zeiss SMT, Jena, Germany
- 10:50 **The Battle Field of Lithography (Keynote)**
L. Pain,
CEA-LETI, Minatec Campus, Genoble, France
[Presentation download to EMLC2018 Exclusive: S02_01](#)
- 11:20 **Multi-Beam Mask Writer – Enabling Tool for EUV Lithography (Invited)**
P. Mayrhofer, C. Klein, E. Platzgummer,
IMS Nanofabrication GmbH, Vienna, Austria
- 11:45 **Multi-beam mask writer MBM-1000 for advanced mask making (Invited)**
H. Matsumoto, H. Yamashita, H. Matsumoto, N. Nakayamada,
NuFlare Technology, Inc., Yokohama, Kanagawa, Japan
[Presentation download to EMLC2018 Exclusive: S02_03](#)
- 12:10-13:20 Lunch Break
- 13:20-15:20 **Session 3 – Wafer Lithography - 193i and EUV**
Chair: J. Finders, ASML Netherlands B.V., Veldhoven, Netherlands
Co-Chair: S. Wurm, ATICE LLC, Albany, NY, USA
- 13:20 **Multi-Trigger Resist for Electron Beam and Extreme Ultraviolet Lithography (Invited)**
C. Popescu^{1,2}, A. McClelland³, G. Dawson³, J. Roth⁴, A.P.G. Robinson^{2,3}
1) Nanoscale Physics, University of Birmingham, UK
2) School of Chemical Engineering, University of Birmingham, UK
3) Irresistible Materials Ltd., Birmingham, UK
4) Nano-C., Westwood, MA, USA
[SPIE Proceedings \[10775-02\]](#)
[Presentation download to EMLC2018 Exclusive: S03_01](#)

- 13:45 **Photonic superlattice multilayers for EUV lithography infrastructure (Invited)**
F. Kuchar, R. Meisels, Montanuniversität Leoben, Austria
[SPIE Proceedings \[10775-03\]](#)
- 14:10 **EUV Pellicle Update (Invited)**
J.-W. van der Horst, D. Brouns, P. Broman, R. Lafarre, T. Modderman, G. Salmaso, ASML Netherlands B.V., Veldhoven, Netherlands
[Presentation download to EMLC2018 Exclusive: S03_03](#)
- 14:35 **NXE:3400B imaging performance assessed from a customer perspective**
G. Schiffelers, F. Wittebrood, C. Legein, ASLM Netherlands B.V., Veldhoven, Netherlands
[Presentation download to EMLC2018 Exclusive: S03_04](#)
- 14:55 **Reticle CDU improvement by Zeiss CDC and the impact on real circuit pattern (Invited)**
R. Seltmann¹, T. Thamm¹, B. Geh⁴, M. D. Kaufmann², A. Bitensky³, A. N. Samy¹, S. Maelzer¹, M. Sczyrba⁵
1) GLOBALFOUNDRIES Dresden, Germany
2) Carl Zeiss SMT GmbH, Oberkochen, Germany
3) Carl Zeiss SMS, D.N. Misgav, Israel
4) Carl Zeiss SMT, Chandler, Arizona, USA
5) Advanced Mask Technology Center GmbH & Co. KG, Dresden, Germany
[Presentation download to EMLC2018 Exclusive: S03_05](#)
- 15:20-15:45 Coffee Break
- 15:45-17:40 **Session 4 – ML2, NIL, and DSA**
Chair: I. Stolberg, Vistec Electron Beam GmbH, Jena, Germany
Co-Chair: B. Connolly, TOPPAN Photomask, Dresden, Germany
- 15:45 **Performance Validation of Mapper's FLX-1200 (Invited)**
J. Pradelles^a, Y. Blancquaert^a, S. Landis^a, L. Pain^a, G. Rademaker^a, I. Servin^a, G. de Boer^b, P. Brandt^b, M. Dansberg^b, R. Jager^b, J. Peijster^b, E. Slot^b, S. Steenbrink^b, M. Wieland^b
a) CEA-LETI, Grenoble, France
b) MAPPER Lithography, Delft, The Netherlands
[SPIE Proceedings \[10775-14\]](#)
- 16:10 **Feasibility of monitoring a multiple e-beam tool using scatterometry and machine learning: CD and stitching error detection**
G. Rademaker^{a,b}, Y. Blancquaert^a, T. Labbaye^a, L. Mourier^a, N. Figueiro^c, F. Sanchez^c, R. Koret^d, J. Pradelles^a, S. Landis^a, S. Rey^a, R. Haupt^c, B. Bringoltz^d, M. Shifrin^d, D. Kandel^d, A. Ger^d, M. Sendelbach^e, S. Wolfling^d, L. Pain^a
a) CEA-LETI, Minatec Campus, Grenoble, France
b) University Grenoble Alpes, Grenoble, France
c) Nova Measuring Instruments GmbH, Dresden, Germany
d) Nova Measuring Instruments, LTD, Rehovot, Israel
e) Nova Measuring Instruments, Inc., Santa Clara, California, USA
[SPIE Proceedings \[10775-36\]](#)
- 16:30 **Wafer-Level UV-Nanoimprint Lithography for high resolution and complex 3D Structures (Invited)**
T. Glinsner¹, M. Eibelhuber¹, G. Berger¹, M. Chouiki¹, C. Lenk², M. Hofmann², S. Lenk², T. Ivanov², I. W. Rangelow², A. Ahmad³, A. Reum³, M. Holz³
1) EV Group, St. Florian am Inn, Austria
2) TU Ilmenau, Germany
3) Nanoanalytik GmbH, Ilmenau, Germany
- 16:55 **Application of rules-based corrections for wafer scale nanoimprint processes and evaluation of predictive models**
H. Teyssedre^a, P. Quemere^a, J. Chartoire^a, F. Delachat^{a,b}, F. Boudaa^a, L. Perraud^a, M. May^a

a) CEA-LETI, Minatec Campus, Grenoble, France;

b) INTITEK, Lyon, France

[SPIE Proceedings \[10775-23\]](#)

[Presentation download to EMLC2018 Exclusive: S04_04](#)

17:15

Silicon nanowires patterning using UV-assisted graphoepitaxy DSA lithography (Invited)

M. Argoud^a, G. Claveau^a, P. Pimenta Barros^a, Z. Chalupa^a, G. Chamiot-Maitral^a, C. Navarro^b, C. Nicolet^b, I. Cayrefourcq^c, R. Tiron^a

a) CEA-LETI, Minatec Campus, Grenoble, France

b) ARKEMA FRANCE, Lacq, France

c) ARKEMA FRANCE, Colombes, France

17:45-18:45

Session 5 – 2nd Part of Poster Presentations

Chair: U. Behringer, UBC Microelectronics, Ammerbuch, Germany

Co-Chair: R. Seltmann, GLOBALFOUNDRIES, Dresden, Germany

POSTER – WAFER LITHOGRAPHY - 193i and EUV

P01 Alternative absorber materials for mitigation of mask 3D effects in high NA EUV lithography

F.J. Timmermans, J. Finders, J. Mcnamara, E. van Setten,
ASML Netherlands B.V., Veldhoven, Netherlands

[SPIE Proceedings \[10775-46\]](#)

[Presentation download to EMLC2018 Exclusive: S05_P01](#)

P02 Advances in multi-layer deposition of EUV mask blanks: Current status and roadmap

K. Rook, S. Kohli, M. Lee, B. Druz, F. Cerio, A. Devasahayam,
Veeco, Plainview, NY, USA

[Presentation download to EMLC2018 Exclusive: S05_P02](#)

P03 Revival of grayscale technique in power semiconductor processing under low-cost manufacturing constraints

J. Schneider, D. Kaiser, N. Morgana, H. Feick
Infineon Technologies Dresden GmbH, Dresden, Germany

[SPIE Proceedings \[10775-21\]](#)

[Presentation download to EMLC2018 Exclusive: S05_P03](#)

P04 Towards Fab Cycle Time Reduction by Machine Learning based Overlay Metrology

F. Hasibi^a, L. van Dijk^a, M. Larranaga^a, A. Lam^b, A. Pastol^a, R. van Haren^a

a) ASML Netherlands B.V., Veldhoven, Netherlands

b) STMicroelectronics, Crolles Cedex, France

[SPIE Proceedings \[10775-53\]](#)

[Presentation download to EMLC2018 Exclusive: S05_P04](#)

POSTER – ML2, NANO-IMPRINT LITHOGRAPHY and DSA

P05 Fabrication of nanoparticles for biosensing using UV-NIL and lift-off

T. Mitteramskogler^a, M. Haslinger^a, A. Shoshi^b, H. Brueckl^b, M. Muehlberger^a

a) PROFACTOR GmbH, Steyr-Gleink, Austria

b) Danube University Krems, Wiener Neustadt, Austria

[SPIE Proceedings \[10775-07\]](#)

P06 Dry etching challenges for high- χ block copolymers

P. Bézard^a, X. Chevalier^b, C. Navarro^b, C. Nicolet^b, G. Fleury^c, I. Cayrefourcq^b, R. Tiron^d,
M. Zelsmann^a

a) University Grenoble Alpes, Grenoble, France

b) ARKEMA, Lacq, France

c) University of Bordeaux, Pessac, France

d) CEA-LETI, Minatec Campus, Grenoble, France

POSTER – MASK PATTERNING, METROLOGY and PROCESS

- P07 Machine learning methods applied to process qualification**
M. Herrmann, S. Meuseman, C. Utzny,
Advanced Mask Technology Center GmbH & Co. KG, Dresden, Germany
[SPIE Proceedings \[10775-04\]](#)
- P08 Deposition Durability of e-Beam Mask Repair**
C. Holfeld^b, T. Göhler^a, P. Nesladek^a, T. Krome^a
a) Advanced Mask Technology Center GmbH & Co. KG, Dresden, Germany
b) GLOBALFOUNDRIES Dresden Module One LLC & Co. KG, Dresden, Germany
[SPIE Proceedings \[10775-12\]](#)
- P09 Nikon's Large-Size Photomask Blanks for Production of High Resolution Panels**
T. Yagami, Y. Takarada, K. Hayashi, T. Ozawa,
Nikon Corporation, Sagamihara, Kanagawa, Japan
- P10 Maximizing Utilization of Large-Scale Mask Data Preparation Clusters**
P. Gilgenkrantz^a, S. Kim^b, W. Han^c, M. Park^b, M. Tsao^b
a) Mentor Graphics (Ireland) Ltd. French Branch, St Ismier, France
b) Mentor Graphics Corp., Fremont, California, USA
c) Mentor Graphics (Korea) LLC., Seongnam-si, Gyeonggi-do, Korea
[SPIE Proceedings \[10775-34\]](#)
- P11 Best Practices Leveling, Vibration and for Reducing Reticle Haze in 193nm Reticle Scanner Environments**
A. Jackson, CyberOptics Semiconductor Division, Minneapolis, MN, USA

POSTER – NON-IC APPLICATIONS, PLASMONICS & PHOTONICS

- P12 ElectroHydroDynamic Lithography for complex polymer structures**
C. Gourgon, J.H. Tortai, J. Boussey, M. Panabière, S. Labau,
Laboratoire des Technologies de la Microélectronique – CNRS-UGA-Minatec,
Grenoble, France
- P13 Plasmonic Resonances in Metal Covered 2D Hexagonal Gratings Fabricated by Interference Lithography**
A. A. Ushkov, M. Bichotte, I. Verrier, T. Kampe, Y. Jourlin,
University Lyon, Saint-Etienne, France
[SPIE Proceedings \[10775-08\]](#)
[Presentation download to EMLC2018 Exclusive: S05_P13](#)
- P14 Approach to combine Electron-Beam Lithography and Two-Photon Polymerization for enhanced nano-channels in network-based biocomputation devices**
D. Reuter^a, S. Steenhusen^b, C. Meinecke^c, G. Heldt^a, M. Groß^b, G. Domann^b, T. Korten^d,
S. E. Schulz^a
a) Fraunhofer ENAS, Chemnitz, Germany
b) Fraunhofer ISC, Würzburg, Germany
c) Technische Universität Chemnitz, Germany
d) Technische Universität Dresden, Germany
[SPIE Proceedings \[10775-37\]](#) [EMLC2018 Best Poster: Danny Reuter](#)

POSTER – MASK2WAFER and WAFER2WAFER METROLOGY

- P15 Limits of model-based CD-SEM metrology**
J. Belissard^a, J. Hazart^a, S. Labbé^b, F. Triki^b
a) CEA-LETI, Grenoble, France
b) University Grenoble Alpes, Saint Martin d'Hères, France
[SPIE Proceedings \[10775-06\]](#)

P16 Manufacturing of roughness standard samples based on ACF/PSD model programming

J. Reche^{a,b}, M. Besacier^b, P. Gergaud^a, Y. Blancquaert^a

a) University Grenoble Alpes, CEA, LETI, DTSI, Grenoble, France

b) University Grenoble Alpes, CNRS, CEA-LETI Minatoc, Grenoble, France

[SPIE Proceedings \[10775-50\]](#)

[Presentation download to EMLC2018 Exclusive: S05_P16](#)

POSTER – USING BIG DATA / DEEP LEARNING

P17 Research on data augmentation for lithography hotspot detection using deep learning

V. Borisov, J. Scheible,

Robert Bosch Center for Power Electronics, Reutlingen University, Germany

[SPIE Proceedings \[10775-35\]](#)

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18:45

Street car or walk to the Cable Car Ground Station

The walking distance from MINATEC Conference Center to the Cable Car Ground Station is about 25 minutes.

19:30-22:00

Conference Dinner at the “Restaurant le Téléférique” on top of the “Bastille” (300m above Grenoble)

after 22:00

From Cable Car ground station individual walk or taxi back to your hotel.

Wednesday, June 20th, 2018

09:00-10:00

Session 6 - 3rd Plenary

Chair: U. Behringer, UBC Microelectronics, Ammerbuch, Germany

09:00

Announcements:

U. Behringer: Best Poster EMLC2018

Jim Wiley: Announcement of SPIE Photomask Technology & EUV Lithography (BACUS) Conference, 17-20 Sept., Monterey, California, USA

09:05

Silicon Photonics: from research to industrial reality (Keynote)

F. Bœuf, STMicroelectronics, Crolles, France

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09:35

Lithography technology and trends for More than Moore devices – Advanced Packaging & MEMS devices (Invited)

A. Pizzagalli, Yole Développement, Lyon, France

[SPIE Proceedings \[10775-45\]](#)

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10:00

Best Paper of Photomask Japan 2018 (Invited)

Development of closed-type EUV pellicle

Y. Ono, k. Kohmura, A. Okubo, D. Taneichi, H. Ishikawa, T. Biyajima
Mitsui Chemicals Inc., Nagaura, Japan

10:25-10:50

Coffee Break

- 10:50-12:30 **Session 7 - Mask Patterning, Metrology and Process**
Chair: M. Tschinkl, AMTC, Dresden, Germany
Co-Chair: K.-D. Roeth, KLA-Tencor MIE, Weilburg, Germany
- 10:50 **Lithographic solution for yield detracting patterning defect signatures caused by Layout and Unit Process Recipe interaction**
M. Voigt, R. Gaertner, R. Seltsmann,
GLOBALFOUNDRIES, Dresden, Germany
[Presentation download to EMLC2018 Exclusive: S07_01](#)
- 11:10 **CK-MASK semi-manual tool for mask inspection and blowing**
A. Leserri, U. Lessi, F. Ferrario,
ST Microelectronics, Agrate, Italy
[SPIE Proceedings \[10775-41\]](#)
- 11:30 **The (almost) completely automated 12"-lithography**
J. Seyfert, L. Albinus, J. Arnold, S. Fritsche, S. Habel, M. Mitrach, M. Stephan,
Infineon Technologies Dresden GmbH, Dresden, Germany
[SPIE Proceedings \[10775-20\]](#)
[Presentation download to EMLC2018 Exclusive: S07_03](#)
- 11:50 **Fast local registration measurements for efficient e-beam writer qualification and correction**
K.-D. Roeth, H. Steigerwald, R. Han, O. Ache, F. Laske,
KLA-Tencor MIE GmbH, Weilburg, Germany
[SPIE Proceedings \[10775-18\]](#) [EMLC2018 Best Paper: Klaus-Dieter Roeth](#)
[Presentation download to EMLC2018 Exclusive: S07_04](#)
- 12:10 **Failure analysis and prevention of patterning issues using OPC simulation and advanced method of contour analysis**
C. Beylier, F. Robert, B. Vianne,
STMicroelectronics, Crolles, France
- 12:30-13:40 Lunch Break
- 13:40-15:00 **Session 8 – Non-IC Applications, Plasmonics & Photonics**
Chair: R. Tiron, CEA-LETI, Grenoble, France
Co-Chair: T. Onanuga, Fraunhofer IISB, Erlangen, Germany
- 13:40 **Accurate determination of 3D PSF and resist effects in grayscale laser lithography**
T. Onanuga^{a,b,c}, C. Kaspar^d, H. Sailer^d, A. Erdmann^{a,b,c}
a) Erlangen Graduate School in Advanced Optical Technologies (SAOT), Germany;
b) Friedrich-Alexander-Universität Erlangen-Nürnberg, LEB, Erlangen, Germany;
c) Fraunhofer Institute for Integrated Systems and Device Technology, Erlangen, Germany;
d) Institut für Mikroelektronik Stuttgart (IMS CHIPS), Stuttgart, Germany
[SPIE Proceedings \[10775-22\]](#)
- 14:00 **Photonic IC Lithography Software - Challenges and Solutions**
N. Ünal^a, U. Hofmann^a, J. Bolten^b, T. Wahlbrink^b, A. L. Giesecke^b, M. Hornung^b,
J. Bolk^c
a) GenISys GmbH, Taufkirchen (Munich), Germany;
b) AMO GmbH, AMICA, Aachen, Germany;
c) Eindhoven University of Technology, NanoLab@TU/e De Zaaie, Eindhoven,
The Netherlands
[Presentation download to EMLC2018 Exclusive: S08_02](#)
- 14:20 **Curvilinear Data Processing Methods and Verification**
C. Browning, S. Postnikov, M. Milléquant, S. Bayle, P. Schiavone
Aseta Nanographics, Grenoble, France
[SPIE Proceedings \[10775-38\]](#)
[Presentation download to EMLC2018 Exclusive: S08_03](#)

- 14:40 **A Resist Reflow 3D Compact Model Approach for Imager Microlens Applications**
S. Bérard-Bergery^a, J. Hazart^a, P. Quéméré^a, C. Beylier^b, N. Allouti^a, M. Cordeau^a,
R. Eleouet^a, F. Tomaso^a, J.-B. Henry^a, A. Ostrovsky^b, V. Rousset^b, V. Farys^b
a) CEA-LETI, Minatec Campus, Grenoble, France,
b) STMicroelectronics, Crolles, France
- 15:00-15:25 Coffee Break
- 15:25-16:45 **Session 9 - Mask2Wafer and Wafer2Wafer Metrology**
Chair: J. H. Peters, bmbg consult, Radebeul, Germany
Co-Chair: F. Weisbuch, GLOBALFOUNDRIES, Dresden, Germany
- 15:25 **Tilted beam SEM, a novel approach for industry 3D metrology**
C. Valade^b, J. Hazart^a, S. Bérard Bergery^a, E. Sungauer^b, M. Besacier^c, C. Gourgon^c
a) University Grenoble Alpes, CEA-LETI, DTSl, Grenoble, France
b) STMicroelectronics, Crolles, France
c) University Grenoble Alpes, CNRS, CEA-LETI, LTM, Grenoble, France
- 15:45 **On the Road to Automated Production Workflows in the Back End of Line**
G. Tabbone, K. Egodage, K. Schulz, A. Garetto,
Carl Zeiss SMT, Jena, Germany
[SPIE Proceedings \[10775-47\]](#)
- 16:05 **Measuring inter-layer edge placement error with SEM contour**
F. Weisbuch, J. Schatz,
GLOBALFOUNDRIES, Dresden, Germany
[SPIE Proceedings \[10775-31\]](#)
[Presentation download to EMLC2018 Exclusive: S09_03](#)
- 16:25 **FEM Simulation of Charging Effect during SEM Methodology**
D. Duc Nguyen^{a,b}, J.-H. Tortai^b, M. Abaidi^a, P. Schiavone^a
a) ASELTA Nanographics, Grenoble, France
b) CEA-LETI, Grenoble, France
[SPIE Proceedings \[10775-42\]](#)
[Presentation download to EMLC2018 Exclusive: S09_04](#)
- 16:45-18:10 **Session 10 – Using Big Data / Deep Learning**
Chair: B. Le Gratiel, STMicroelectronics, Crolles, France
Co-Chair: S. A. Savari, Texas A&M University, College Station, TX, USA
- 16:45 **Automatic Defect Classification of SEM images using Deep Learning (Invited)**
L. Bidault, D. Mastroeni,
STMicroelectronics Rousset, France
[Presentation download to EMLC2018 Exclusive: S10_01](#)
- 17:10 **Deep Supervised Learning to Estimate True Rough Line Images from SEM Images**
N. Chaudhary, S. A. Savari, S. S. Yeddulapalli,
Texas A&M University, College Station, TX, USA
[SPIE Proceedings \[10775-15\]](#) [EMLC2018 2nd Best Paper: Sarap A. Savari](#)
[Presentation download to EMLC2018 Exclusive: S10_02](#)
- 17:30 **Microlens under Melt In-Line Monitoring based on application of Neural Network Automatic Defect Classification**
J. Ducoté^a, A. Lakcher^a, L. Bidault^b, A.-R. Philipot^a, B. Le-Gratiel^a
a) STMicroelectronics, Crolles, France
b) STMicroelectronics, Rousset, France
[SPIE Proceedings \[10775-24\]](#)
[Presentation download to EMLC2018 Exclusive: S10_03](#)

17:50 **Machine Learning applications in overlay prediction**
A. Lam,
STMicroelectronics, Crolles, France
[Presentation download to EMLC2018 Exclusive: S10_04](#)

18:10 **Thanks to EMLC2018 participants & Announcement of EMLC2019**
U. Behringer, UBC Microelectronics, Ammerbuch, Germany

18:15 **End of EMCL2018 Conference**